

Notice of References Cited

Application/Control No.

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Applicant(s)/Patent Under

Reexamination

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Examiner

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Art Unit

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U.S. PATENT DOCUMENTS

*	Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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NON-PATENT DOCUMENTS

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U	Ohtaki, Michitaka, Sayaka Maehara, and Shinichiro Shinge. "Thermoelectric Properties of Al-doped ZnO Sintered With Nanosized Void Forming Agents." Proc. of 22nd International Conference on Thermoelectrics. IEEE 2003: 171-74.
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